

# Ground-Bounce Reduction in Narrow-Band RF Front-Ends



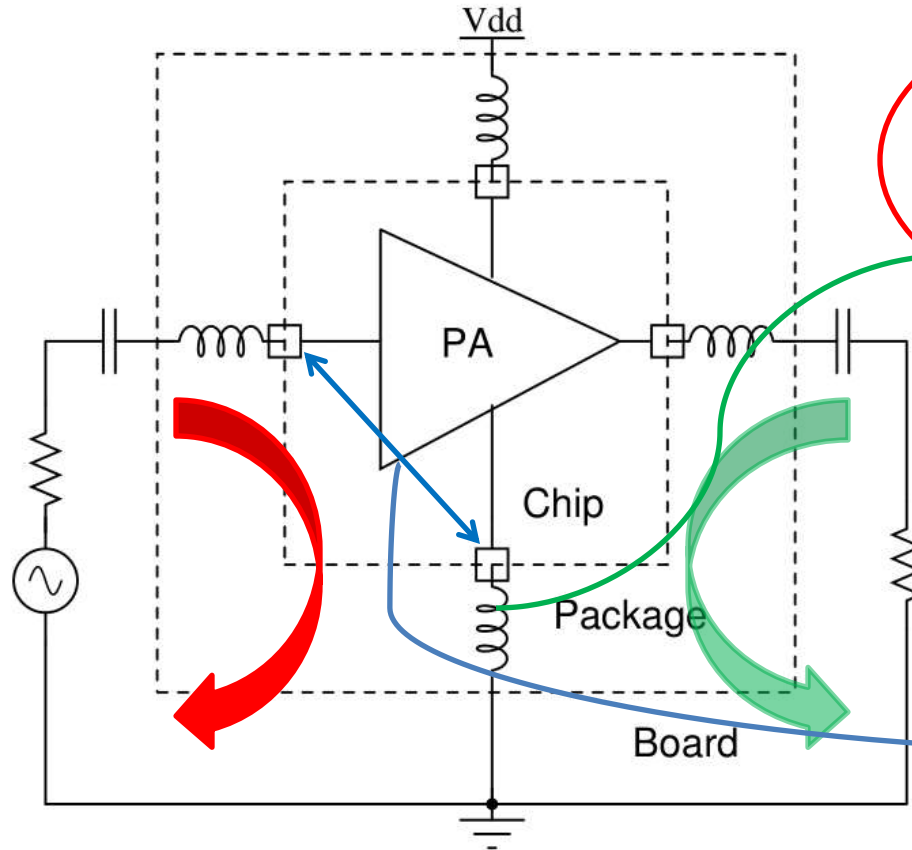
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# Outline

- Ground-bounce in RFICs
  - Effect on impedance-matching and stability
- Reducing ground-bounce in narrowband RF circuits
- Reducing PA sensitivity to switching noise
- Summary

# Motivation for this work

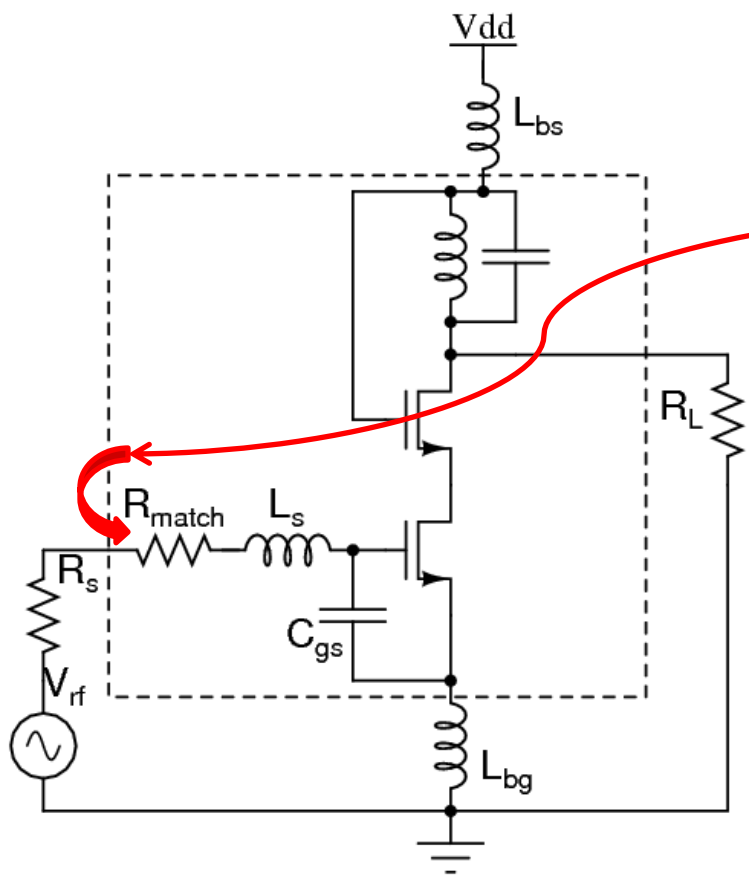
# Ground-bounce in RFICs



Current through ground bond wire due to output circuit

PA input different from external input

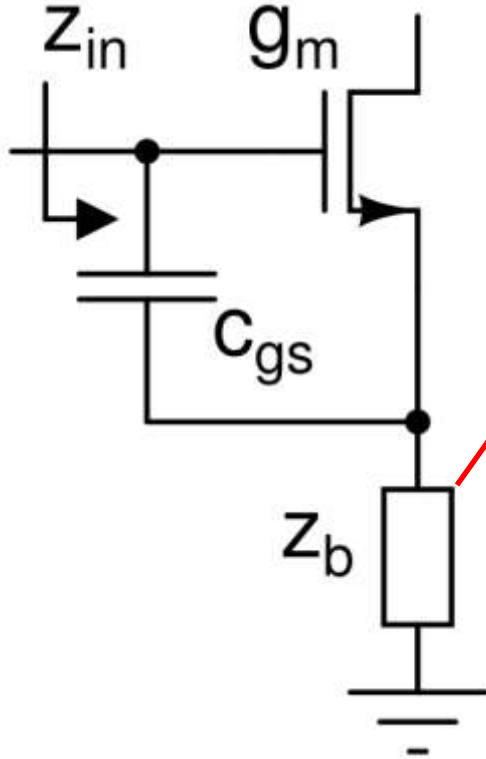
# Matching



Input impedance becomes a function of transistor transconductance

Transistor parameters change with power level

# Stability



$$Z_{in} = \frac{1}{j\omega C_{gs}} + Z_b + \frac{g_m Z_b}{j\omega C_{gs}}$$

$Z_b$  becomes capacitive at high frequencies

Negative real term causing instability

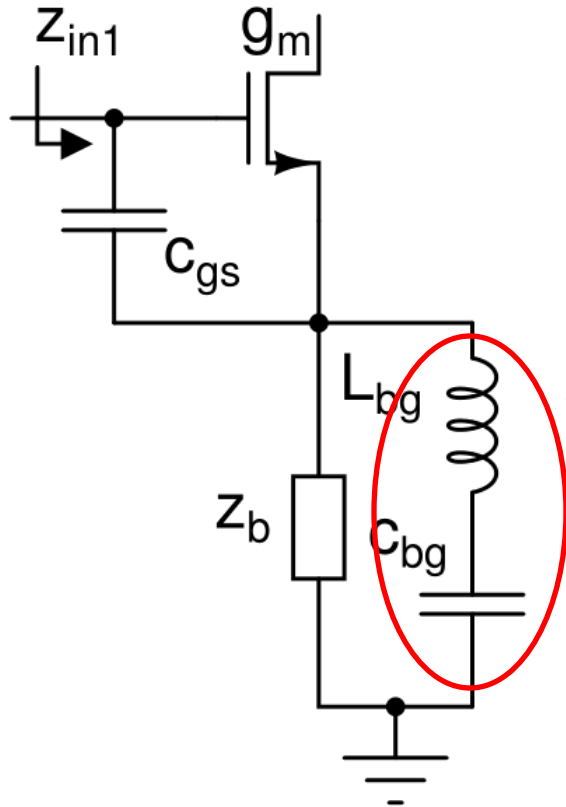
# PA ground bounce reduction

# Reducing ground-bounce (conventional)

- Minimize bond-wire inductance
  - Multiple bond-wires in parallel
  - Reducing bond-wire length by placing die at an offset from centre
- Differential implementation
- On chip supply decoupling capacitor



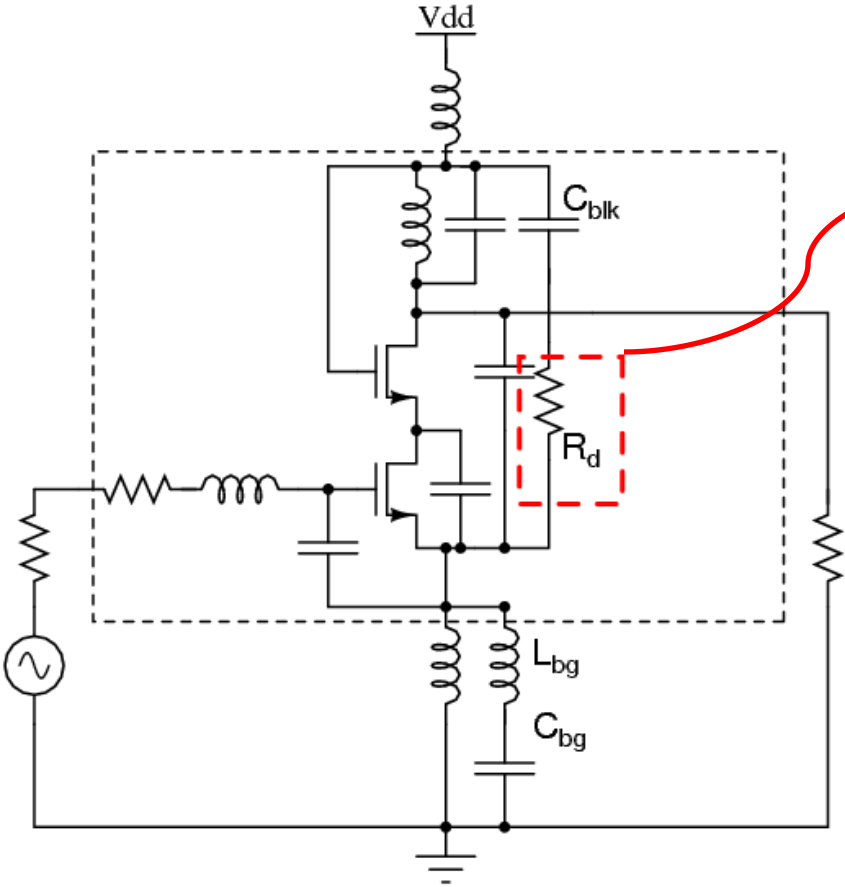
# Reducing ground-bounce (proposed)



Extra bond-wire and  
off chip cap in  
parallel with primary  
ground path

No ground bounce  
at series  
resonance

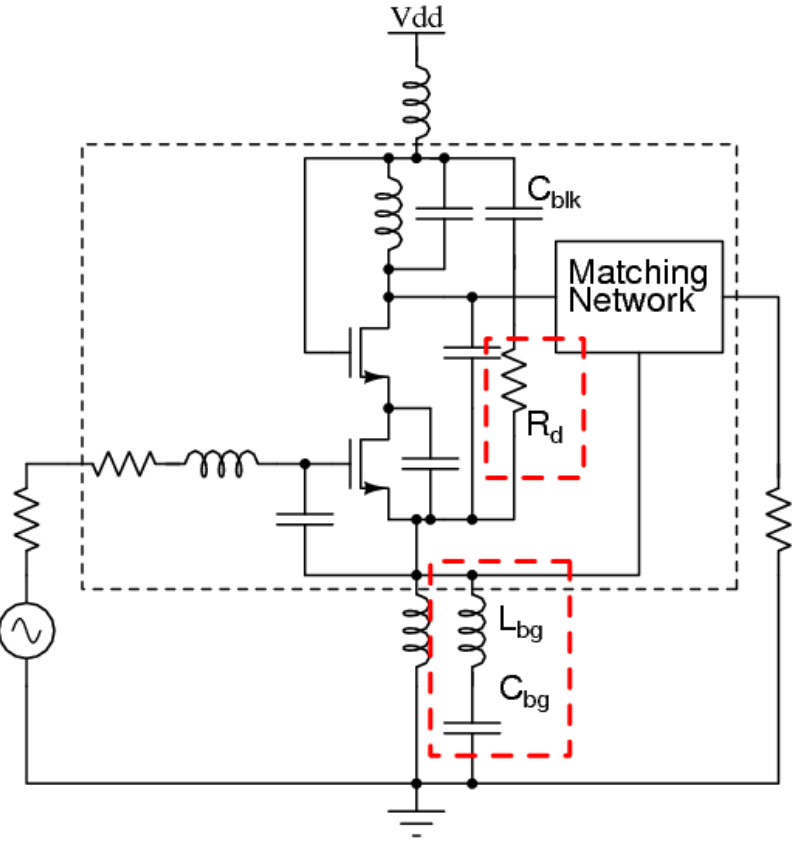
# Stabilization



Resistance  
added in non  
signal path

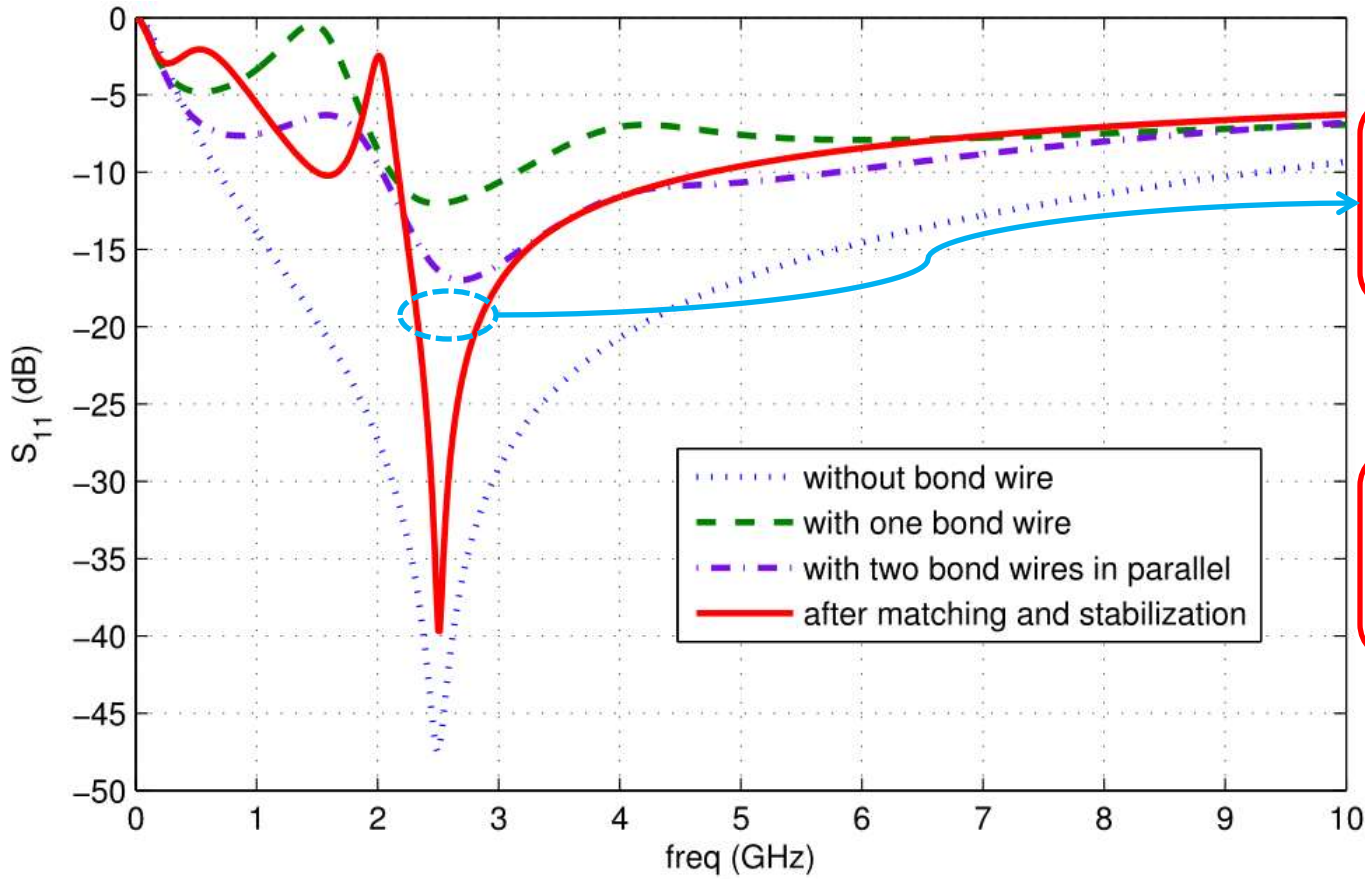
Reduces Q,  
improves stability

# Simulation – series resonance



- 2.5GHz PA with 16dBm P1dB in 130nm CMOS
- Bond-wire: 2nH,  $Q=100$  (worst-case)

# Simulation – Input matching

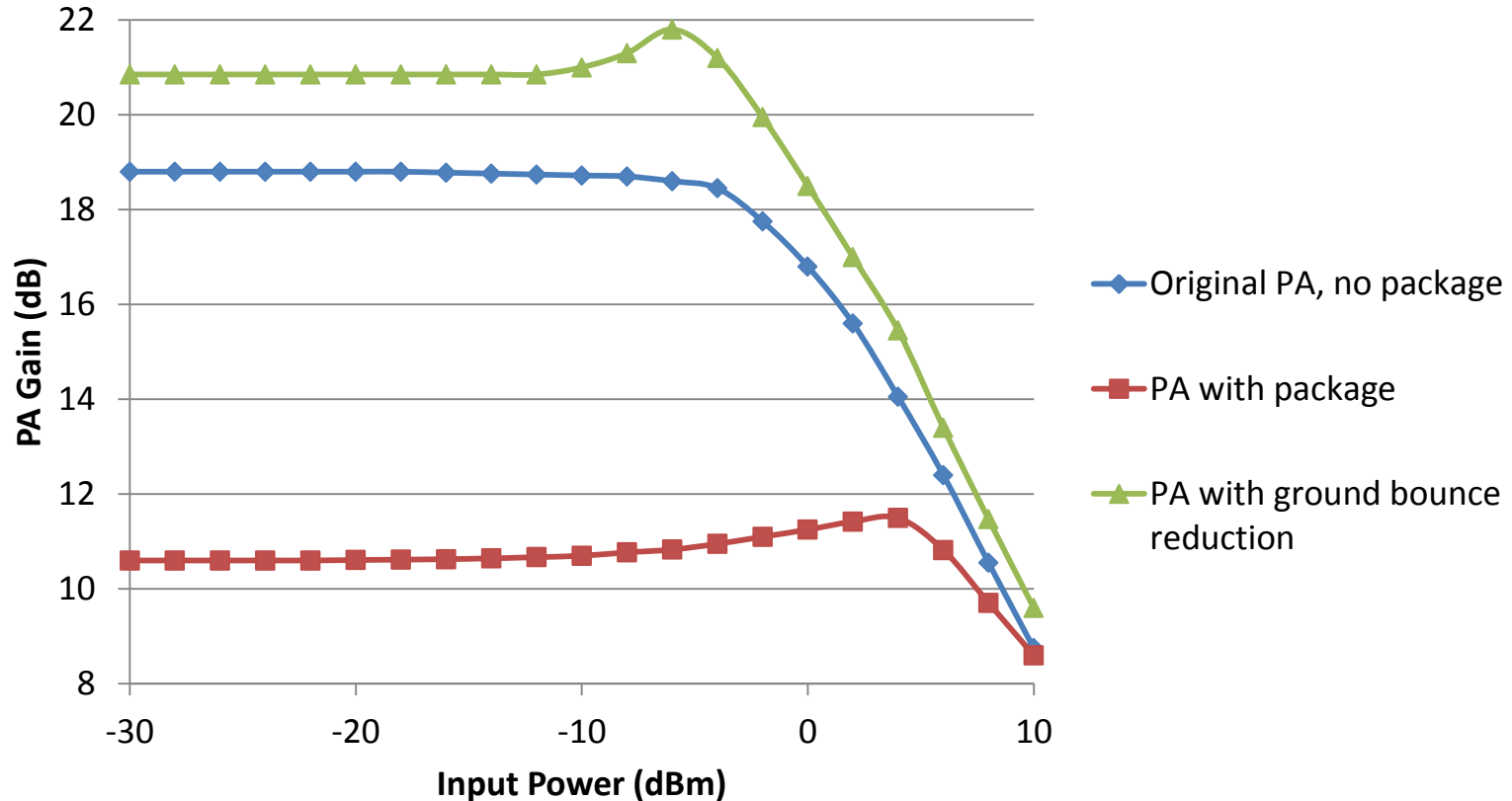


Input matching  
better than 20dB  
over 500MHz BW

$S_{11} < 0$ dB at all  
frequencies →  
stable

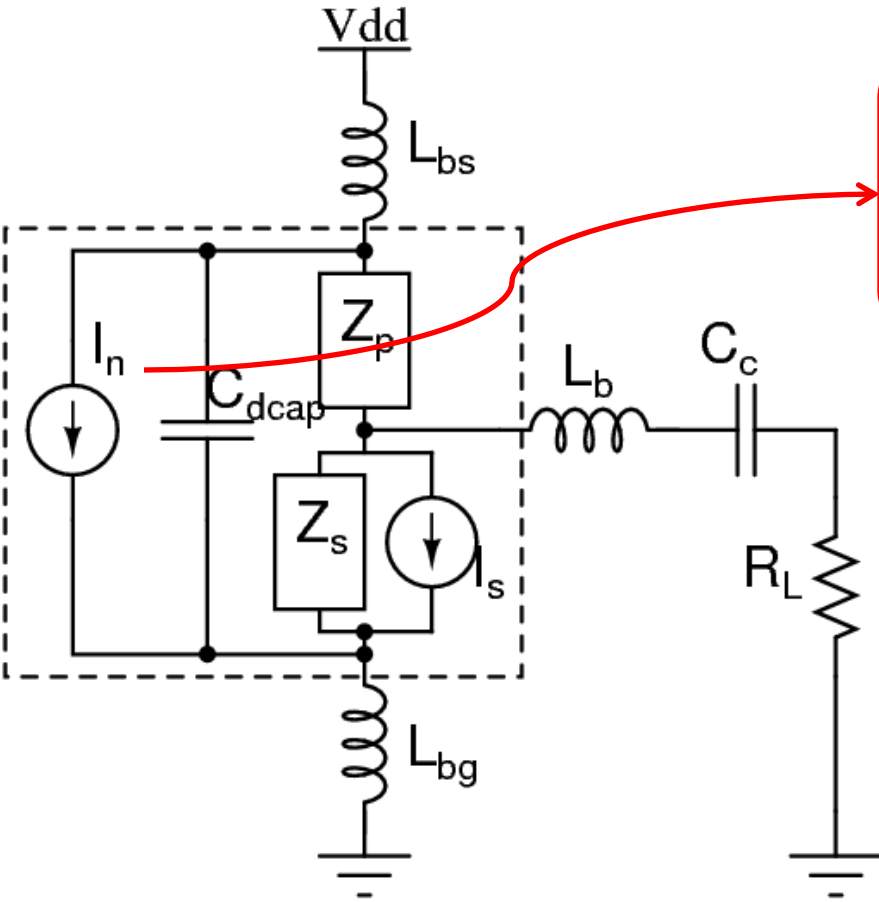
# Simulation – PA gain

## PA gain vs input power



# PA sensitivity to switching noise

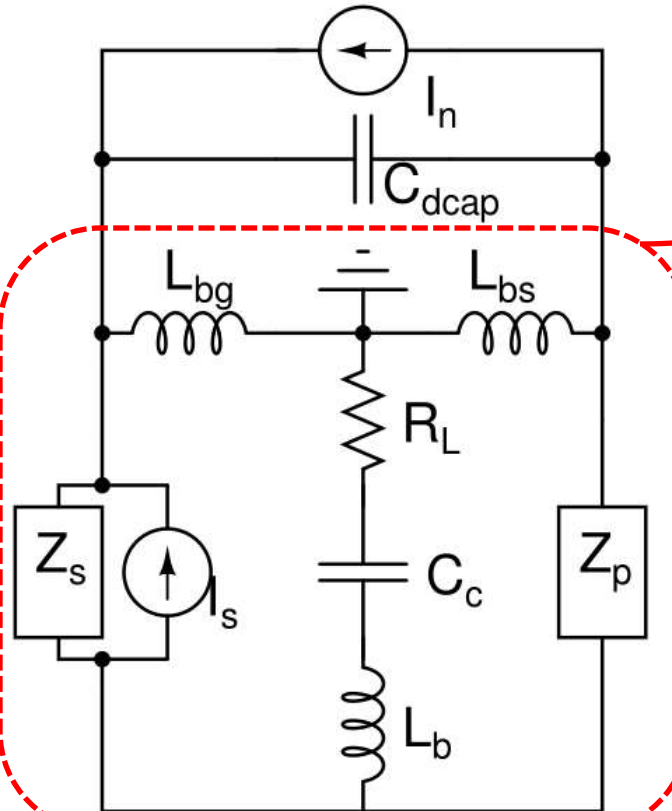
# Effect of switching noise



Current drawn by on-chip circuitry causes ground bounce

**Desired:** Full signal current  $I_s$  through load while isolating from  $I_n$

# Impedance balance



Forms a bridge with  $I_n$  as source

$$\frac{\omega L_{bg}}{\omega L_{bs}} = \frac{Z_s}{Z_p}$$

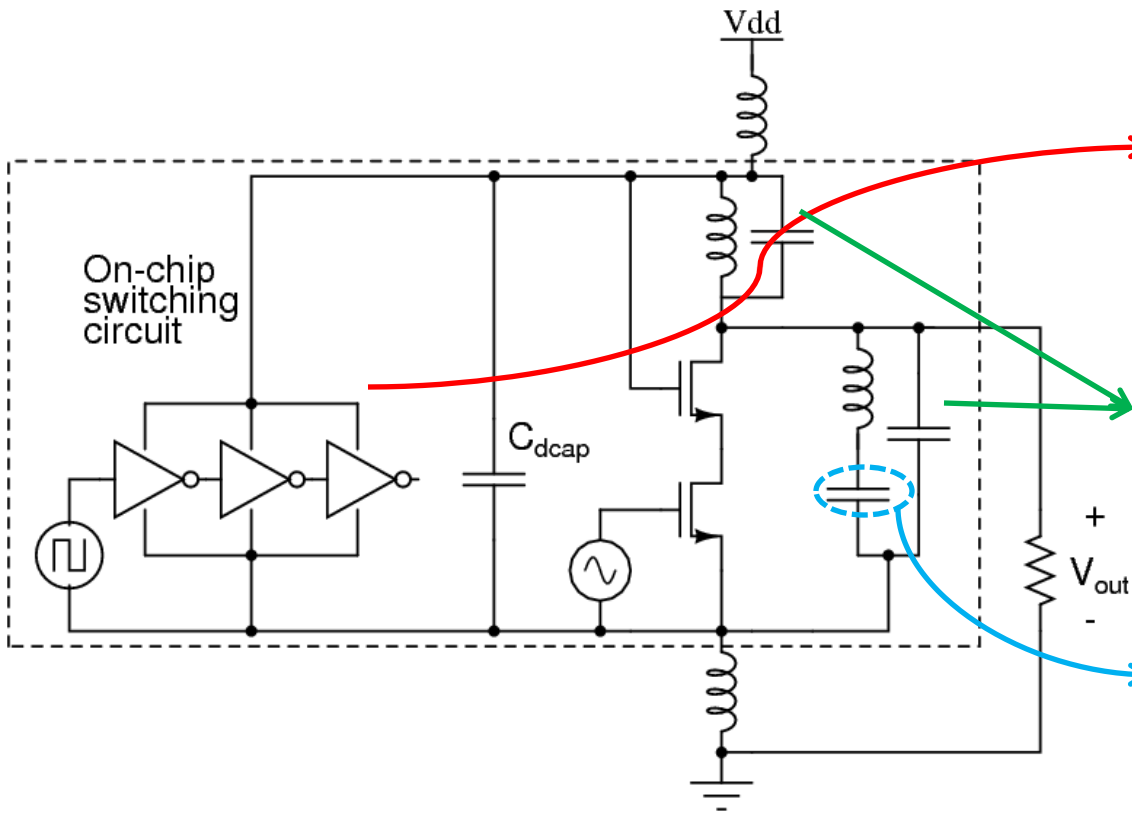
Balanced Bridge

$C_c$  optimized to maximize power transfer from  $I_s$  to  $R_L$

No effect of  $I_n$  on  $R_L$

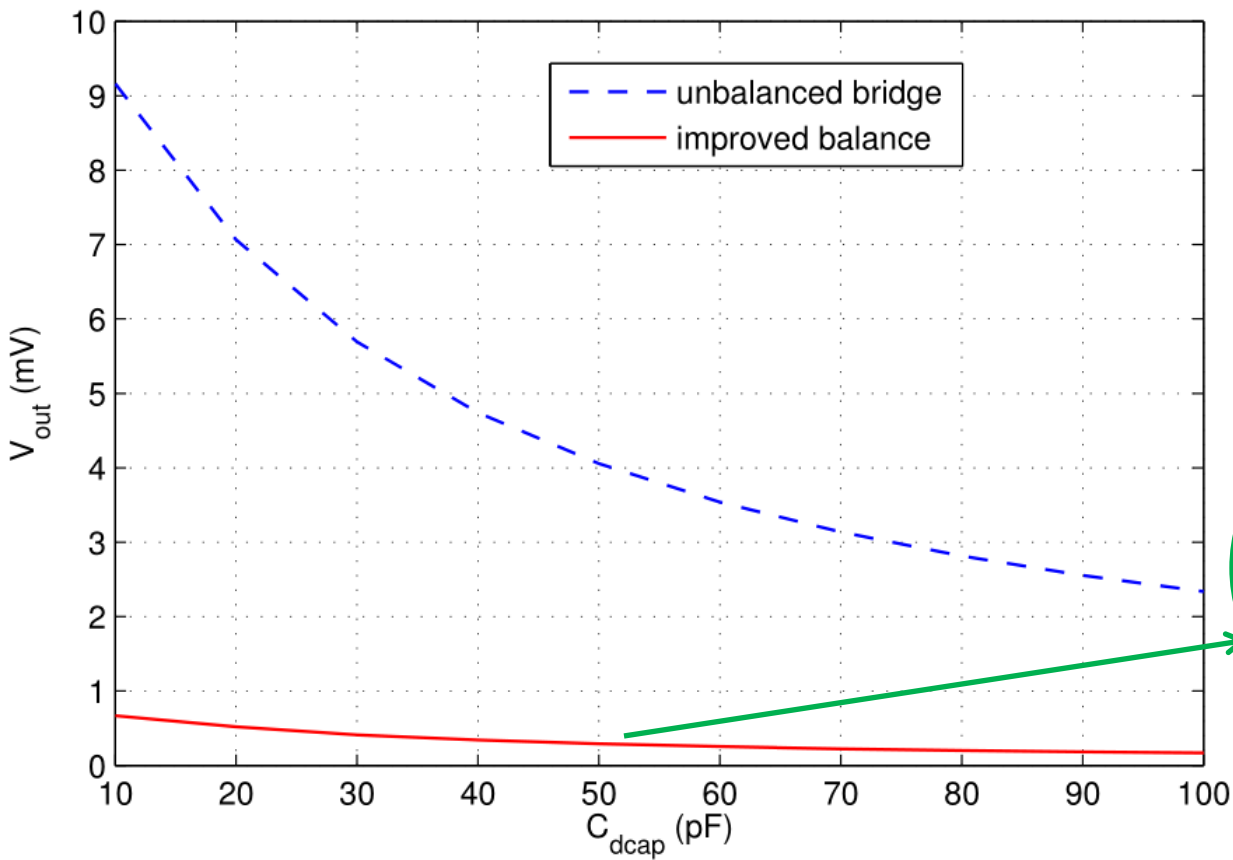


# Simulation – switching noise



- Same PA as before
- Three inverters to generate switching noise
- Impedance balanced at PA o/p using two tanks
- Series cap to prevent dc short between rails

# Simulation – output noise



Noise amplitude  
from PSS sim

Improved  
balance →  
Noise reduced  
with small de-  
cap

# Summary

- Significant ground-bounce reduction is possible in narrow-band RF front-ends using the proposed series-resonance technique
  - Uses extra ground pin and one external capacitor
- Impedance balance in output stage can suppress noise added by on-chip circuitry

# Thank You

Questions?